

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTOR NP80N06MLG, NP80N06NLG, NP80N06PLG

SWITCHING N-CHANNEL POWER MOS FET

DESCRIPTION

The NP80N06MLG, NP80N06NLG, and NP80N06PLG are N-channel MOS Field Effect Transistors designed for high current switching applications.

ORDERING INFORMATION

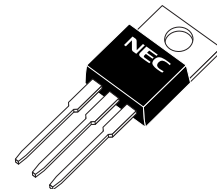
PART NUMBER	LEAD PLATING	PACKING	PACKAGE
NP80N06MLG-S18-AY ^{Note}	Pure Sn (Tin)	Tube	TO-220 (MP-25K) typ. 1.9 g
NP80N06NLG-S18-AY ^{Note}		50 p/tube	TO-262 (MP-25SK) typ. 1.8 g
NP80N06PLG-E1B-AY ^{Note}		Tape	TO-263 (MP-25ZP) typ. 1.5 g
NP80N06PLG-E2B-AY ^{Note}		1000 p/reel	

Note Pb-free (This product does not contain Pb in the external electrode.)

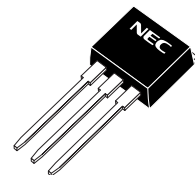
FEATURES

- Logic level
- Built-in gate protection diode
- Super low on-state resistance
 - NP80N06MLG, NP80N06NLG
 - $R_{DS(on)1} = 8.6 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 40 \text{ A)}$
 - $R_{DS(on)2} = 13.3 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 35 \text{ A)}$
 - NP80N06PLG
 - $R_{DS(on)1} = 8.3 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 40 \text{ A)}$
 - $R_{DS(on)2} = 13 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 35 \text{ A)}$
- High current rating
 - $I_{D(DC)} = \pm 80 \text{ A}$
- Low input capacitance
 - $C_{iss} = 4600 \text{ pF TYP.}$
- Designed for automotive application and AEC-Q101 qualified

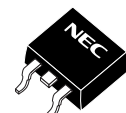
(TO-220)



(TO-262)



(TO-263)



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ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$)

Drain to Source Voltage ($V_{GS} = 0\text{ V}$)	V_{DSS} 60		V
Gate to Source Voltage ($V_{DS} = 0\text{ V}$)	V_{GSS}	$\pm 20\text{ V}$	
Drain Current (DC) ($T_C = 25^\circ\text{C}$)	$I_{D(DC)}$	$\pm 80\text{ A}$	
Drain Current (pulse) ^{Note1}	$I_{D(pulse)}$	$\pm 180\text{ A}$	
Total Power Dissipation ($T_C = 25^\circ\text{C}$)	P_{T1} 115		W
Total Power Dissipation ($T_A = 25^\circ\text{C}$)	P_{T2} 1.	8	W
Channel Temperature	T_{ch} 175		$^\circ\text{C}$
Storage Temperature	T_{stg}	$-55\text{ to }+175$	$^\circ\text{C}$
Repetitive Avalanche Current ^{Note2}	I_{AR} 32		A
Repetitive Avalanche Energy ^{Note2}	E_{AR} 102		mJ

Notes 1. $PW \leq 10\text{ }\mu\text{s}$, Duty Cycle $\leq 1\%$

2. $T_{ch} \leq 150^\circ\text{C}$, $R_G = 25\text{ }\Omega$

THERMAL RESISTANCE

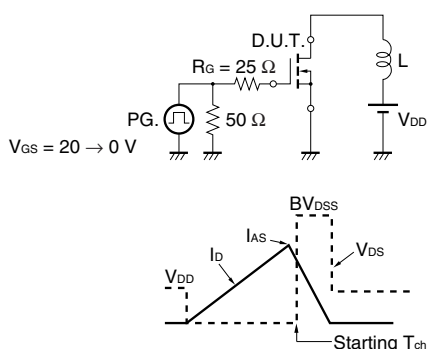
Channel to Case Thermal Resistance	$R_{th(ch-C)}$ 1.3	0	$^\circ\text{C/W}$
Channel to Ambient Thermal Resistance	$R_{th(ch-A)}$ 83.3		$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

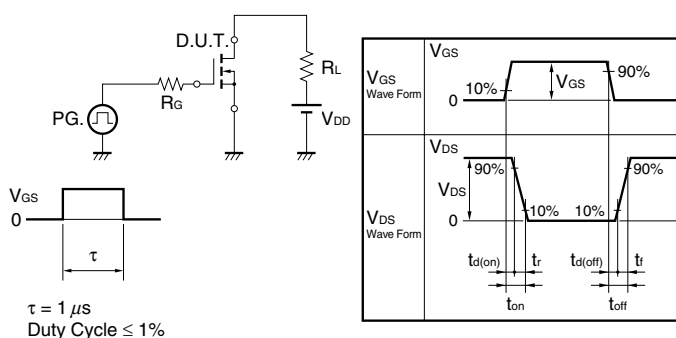
CHARACTERISTICS SY	MBOL	TEST CONDITIONS M	IN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 60 V, V _{GS} = 0 V			1	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±20 V, V _{DS} = 0 V			±10	μA
Gate to Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.4	2.5		V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 5 V, I _D = 35 A	25	59		S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)1}	V _{GS} = 10 V, I _D = 40 A NP80N06MLG, NP80N06NLG		6.7	8.6	mΩ
		V _{GS} = 10 V, I _D = 40 A NP80N06PLG		6.2	8.3	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 35 A NP80N06MLG, NP80N06NLG		8.4	13.3	mΩ
		V _{GS} = 4.5 V, I _D = 35 A NP80N06PLG		7.6	1	3
Input Capacitance	C _{iss}	V _{DS} = 25 V, V _{GS} = 0 V, = 1 MHz		4600	6900	pF
Output Capacitance	C _{Oss}		370		560	pF
Reverse Transfer Capacitance	C _{rss} f		220		400	pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 30 V, I _D = 40 A, V _{GS} = 10 V, R _G = 0 Ω		17	37	ns
Rise Time	t _r			13	33	ns
Turn-off Delay Time	t _{d(off)}		70		140	ns
Fall Time	t _f		7		18	ns
Total Gate Charge	Q _G	V _{DD} = 48 V, V _{GS} = 10 V, I _D = 80 A	85		128	nC
Gate to Source Charge	Q _{GS}		14			nC
Gate to Drain Charge	Q _{GD}		25			nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 80 A, V _{GS} = 0 V	0.96		1.5	V
Reverse Recovery Time	t _{rr}	I _F = 80 A, V _{GS} = 0 V,		41		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs	56			nC

Note Pulsed test

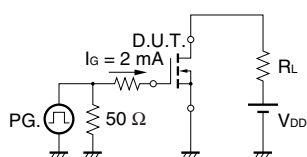
TEST CIRCUIT 1 AVALANCHE CAPABILITY



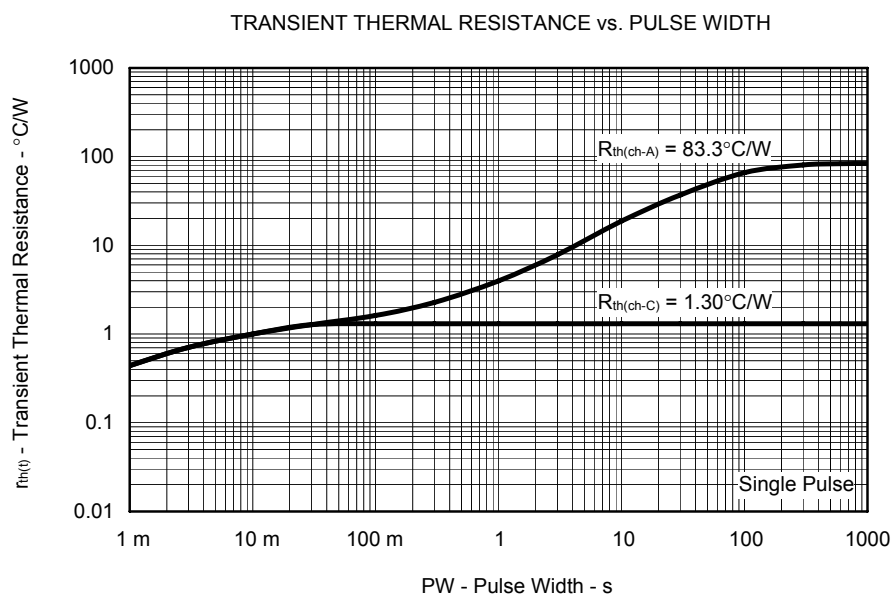
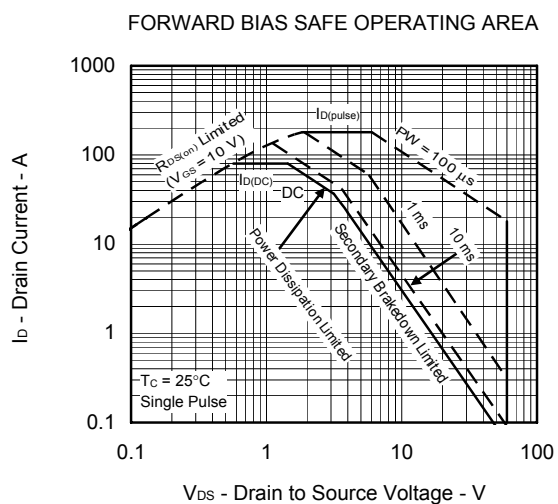
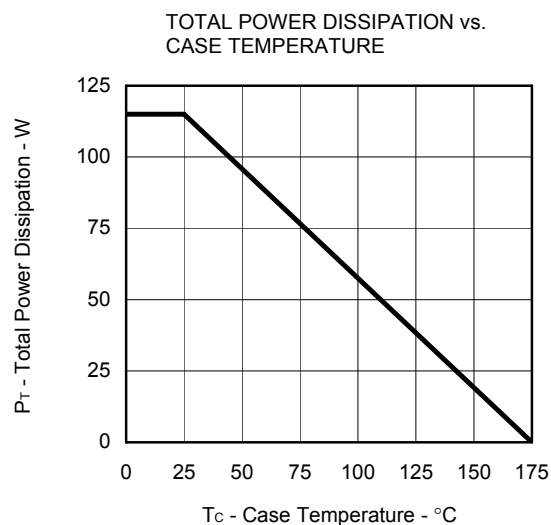
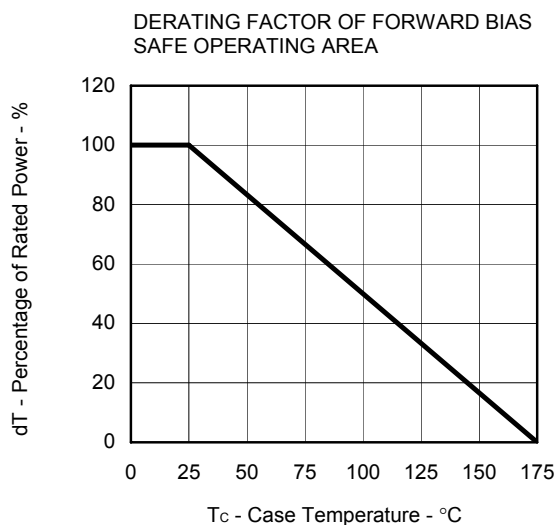
TEST CIRCUIT 2 SWITCHING TIME

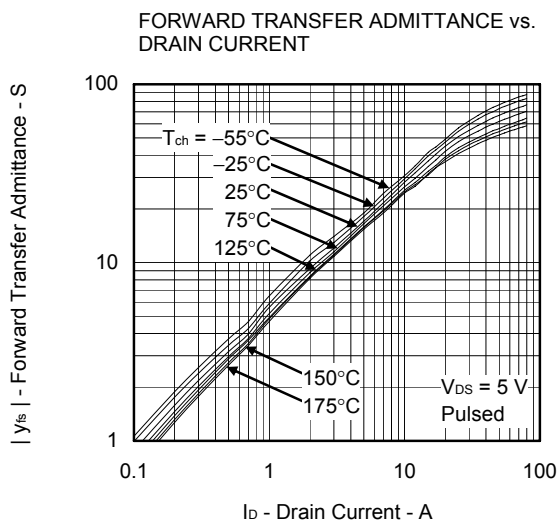
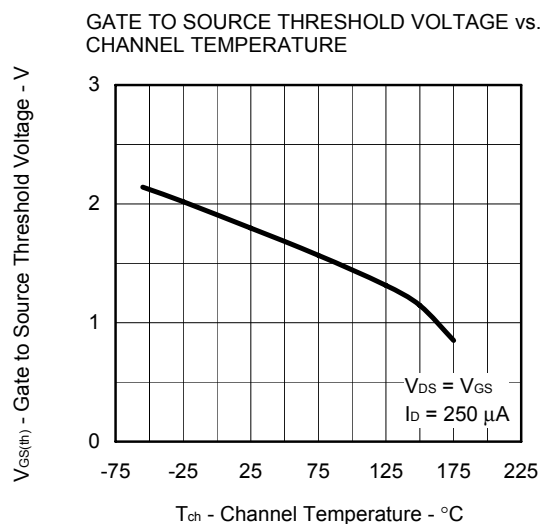
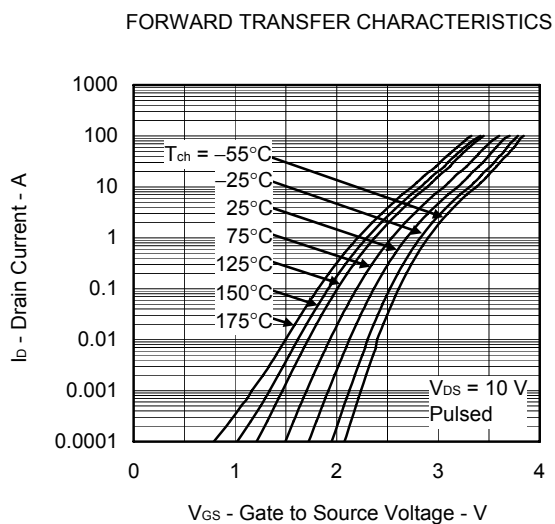
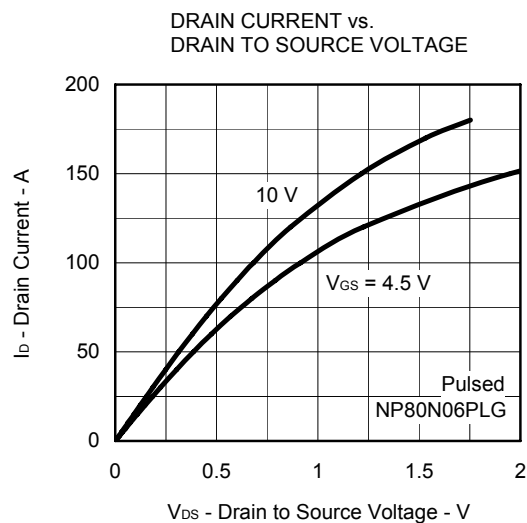
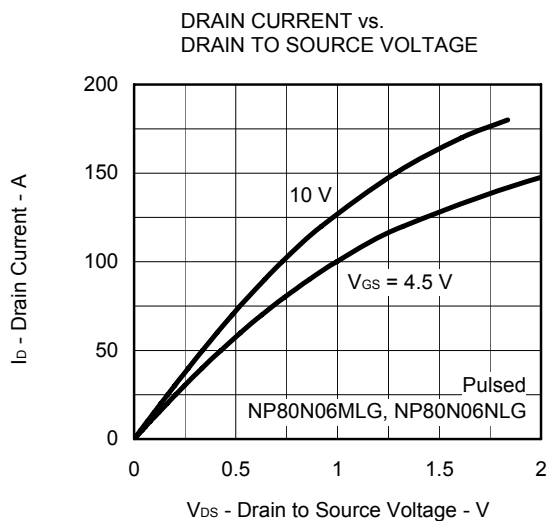


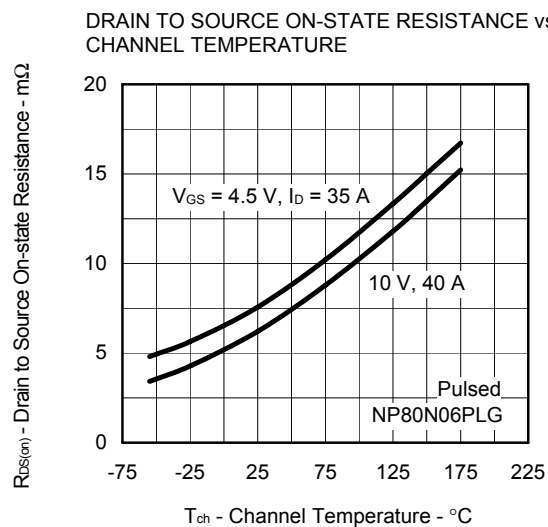
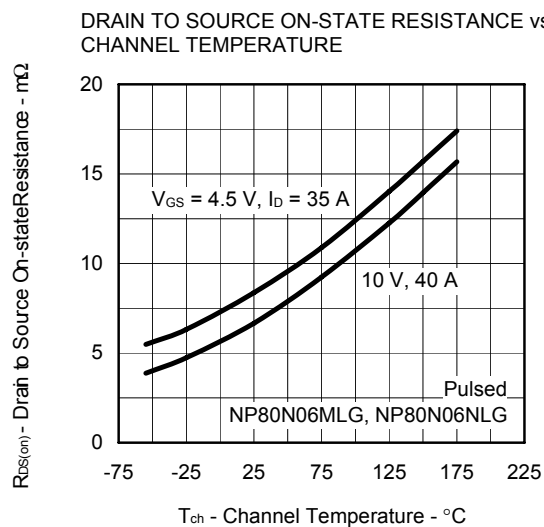
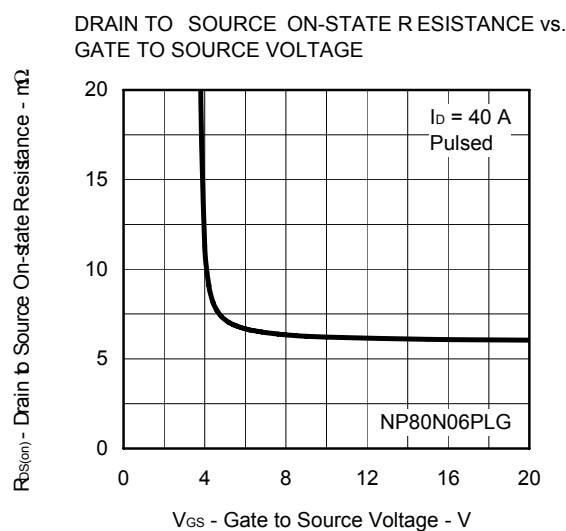
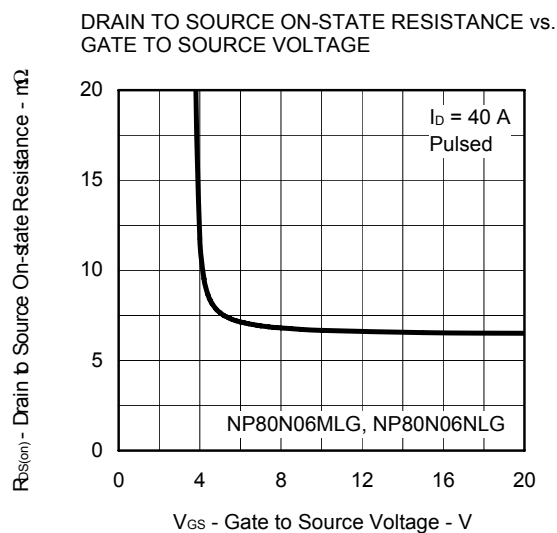
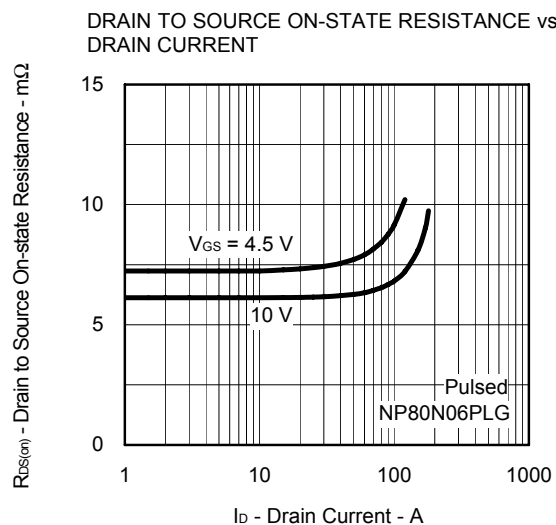
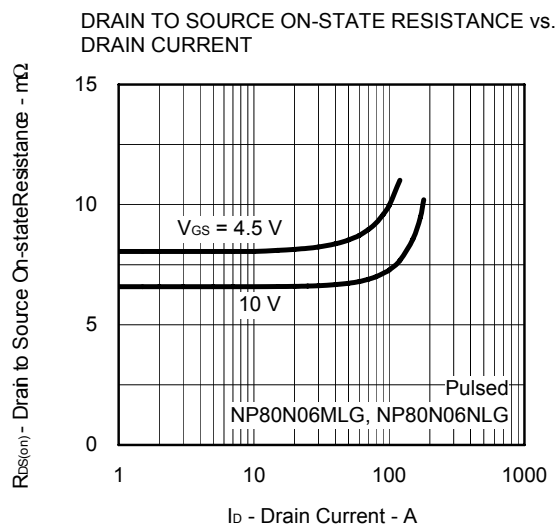
TEST CIRCUIT 3 GATE CHARGE



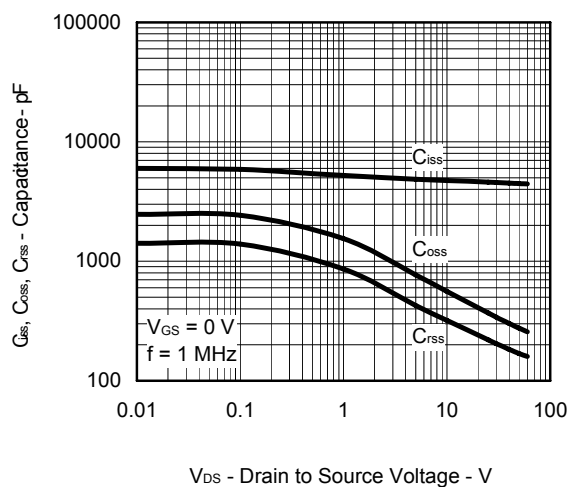
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$)



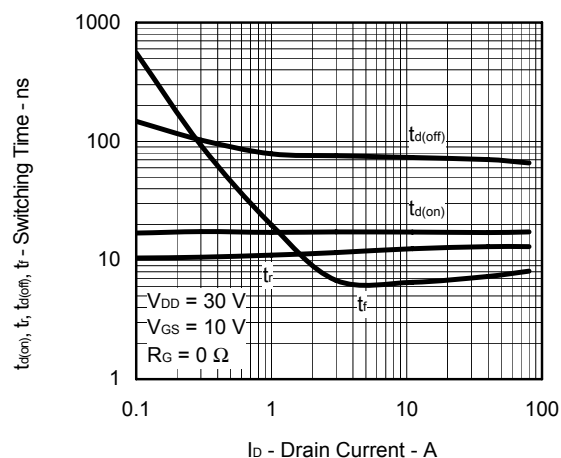




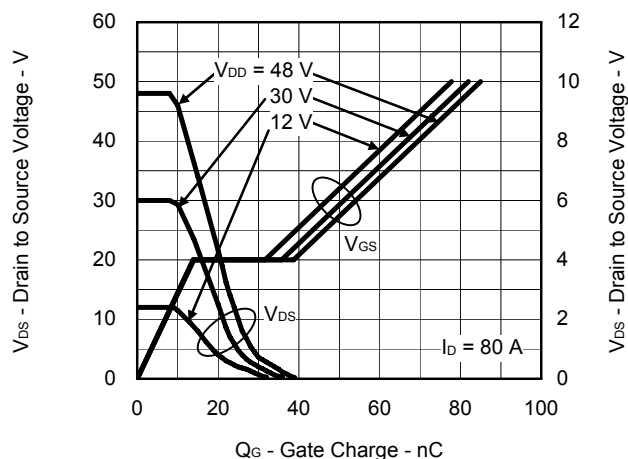
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



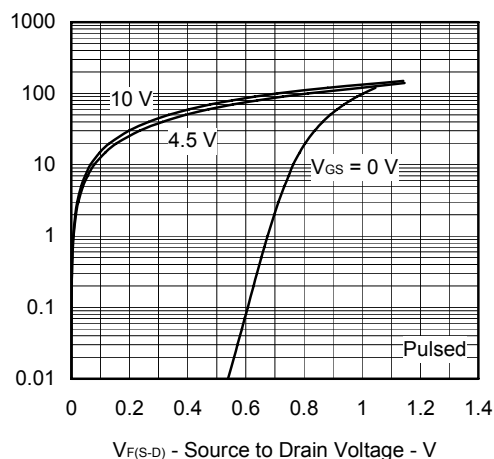
SWITCHING CHARACTERISTICS



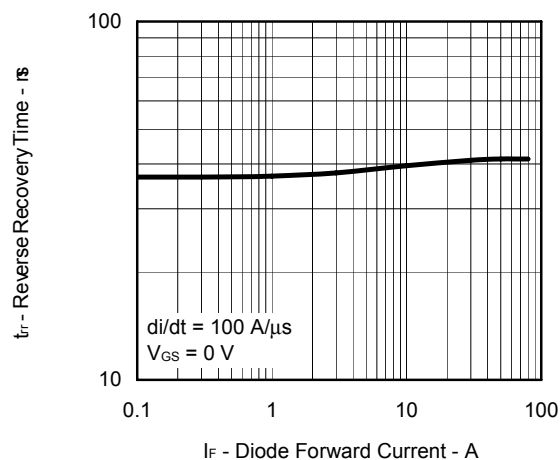
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

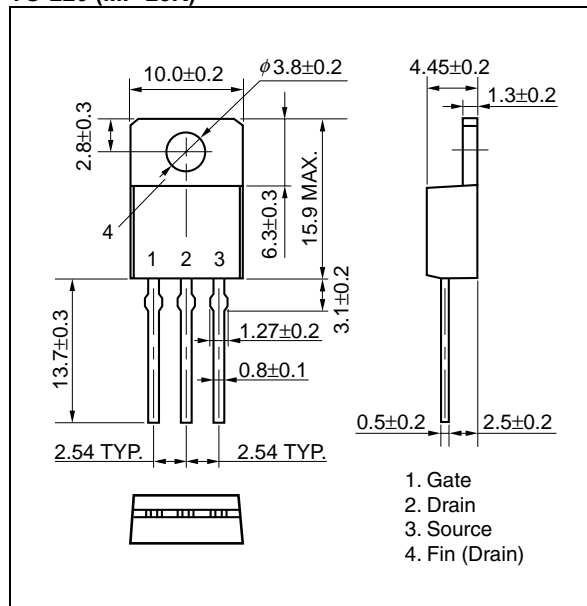


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

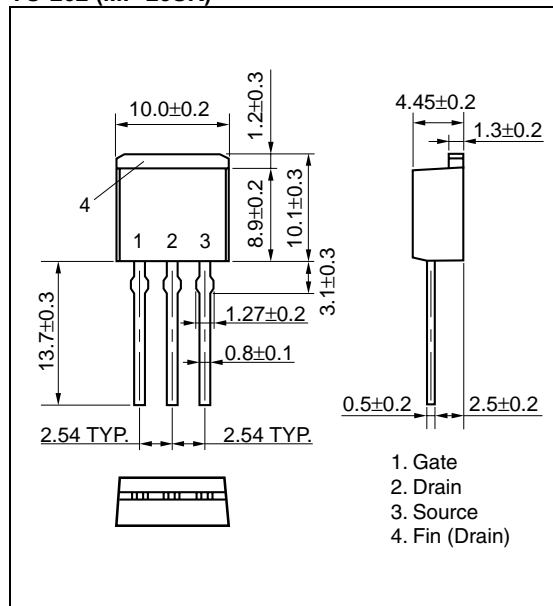


PACKAGE DRAWINGS (Unit: mm)

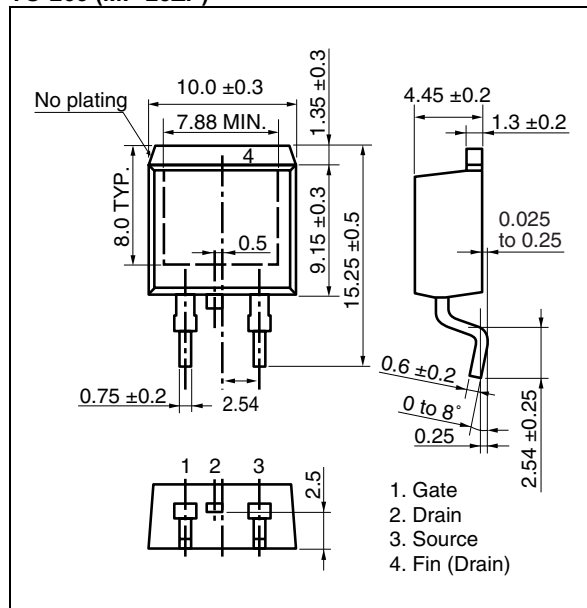
TO-220 (MP-25K)



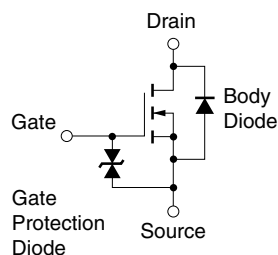
TO-262 (MP-25SK)



TO-263 (MP-25ZP)



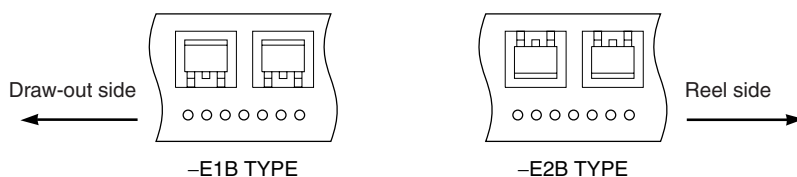
EQUIVALENT CIRCUIT



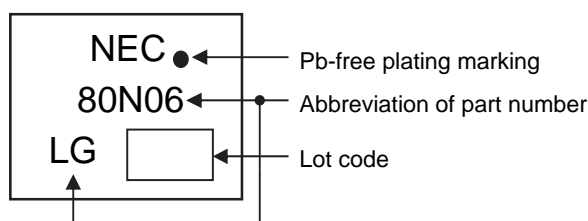
Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

TAPE INFORMATION (NP80N06PLG)

There are two types (-E1B, -E2B) of taping depending on the direction of the device.



MARKING INFORMATION



RECOMMENDED SOLDERING CONDITIONS

These products should be soldered and mounted under the following recommended conditions.

For soldering methods and conditions other than those recommended below, please contact an NEC Electronics sales representative.

For technical information, see the following website.

Semiconductor Device Mount Manual (<http://www.necel.com/pkg/en/mount/index.html>)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow NP80N06PLG	Maximum temperature (Package's surface temperature): 260°C or below Time at maximum temperature: 10 seconds or less Time of temperature higher than 220°C: 60 seconds or less Preheating time at 160 to 180°C: 60 to 120 seconds Maximum number of reflow processes: 3 times Maximum chlorine content of rosin flux (percentage mass): 0.2% or less	IR60-00-3
Wave soldering NP80N06MLG, NP80N06NLG	Maximum temperature (Solder temperature): 260°C or below Time: 10 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	THDWS
Partial heating NP80N06MLG, NP80N06NLG, NP80N06PLG	Maximum temperature (Pin temperature): 350°C or below Time (per side of the device): 3 seconds or less Maximum chlorine content of rosin flux: 0.2% (wt.) or less	P350

Caution Do not use different soldering methods together (except for partial heating).

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